On electron heating in magnetron sputtering discharges

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Introduction

- Magnetron sputtering has been a highly successfull technique that has a number of industrial applications
- A magnet is placed at the back of the cathode target with the pole pieces at the center and perimeter
- The magnetic field confines the energetic electrons near the cathode
- The electrons undergo numerous ionizing collisions before being lost to a grounded surface





Introduction

- The conventional wisdom is that plasma generation is based on the supply of energy via secondary electrons (SEs) accelerated from the target
- However, one of the remaining fundamental questions is how electrons are heated in the magnetron sputtering discharge



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dc magnetron sputtering discharge





T. J. Petty, LPGP, Université Paris Sud

- A dc discharge with a cold cathode is sustained by secondary electron emission from the cathode by ion bombardment
- The discharge current at the target consists of electron current $I_{\rm e}$ and ion current $I_{\rm i}$ or

$$I_{\rm D} = I_{\rm e} + I_{\rm i} = I_{\rm i}(1 + \gamma_{\rm SE})$$

where $\gamma_{\rm SE}$ is the secondary electron emission coefficient

• Note that $\gamma_{SE} \sim 0.05 - 0.2$ for most metals, so at the target, the dominating fraction of the discharge current is ion current



- These secondary electrons are accelerated in the cathode dark space – referred to as primary electrons
- They must produce sufficient number of ions to release more electrons from the cathode
- The number of electron-ion pairs created by each secondary electron is then

$$\mathcal{N} \approx \frac{V_{\rm D}}{\mathcal{E}_{\rm c}}$$

where \mathcal{E}_c is the energy loss per electron-ion pair created







 To account for the electrons that are not trapped we define an effective secondary electron emission coefficient

$$\gamma_{\rm SE,eff} = m\epsilon_{\rm e}(1-r)\gamma_{\rm SE}$$

- *ϵ*_e is the fraction of the electron energy that is used for ionization before being lost
- *m* is a factor that accounts for secondary electrons ionizing in the sheath
- *r* is the recapture probability of secondary electrons



 To sustain the discharge the condition

 $\gamma_{\rm SE, eff} \mathcal{N} = 1$

has to be fulfilled

 This defines the minimum voltage to sustain the discharge as

$$V_{\rm D,min} = \frac{\mathcal{E}_{\rm c}}{\beta \gamma_{\rm SE,eff}}$$

referred to as Thornton equation

 β is the fraction of ions that return to the cathode

Magnetron sputtering: basic physics and application to cylindrical magnetrons

John A. Thornton

Telic Corporation, 1631 Colorado Avenue, Santa Monica, California 90404 (Received 22 September 1977; accepted 7 December 1977)

Magnetron sputtering sources can be defined as sloed devices in which magnetic fields are used in concert with the cathods united to form detector targe which are so configured that the EXB detector-defit currents close on themselves. Cassial cylindrical magneton sputtering proceed for a site of the start concert of the site of the start process of the start of the sputtering rates can be obtained, nearly independent of voltage, even at low pressures. This characterizes what has been defined as the magnetorin model of operation. The spart reviews with particular emphasis on sylindrical magnetorus. The important attributes of these devices as sputtering source are also reviewd.

PACS numbers: 81.15.-z, 52.75.-d

Thornton (1978) JVST 15(2) 171



- The basic assumption is that acceleration across the sheath is the main source of energy for the electrons
- Above breakdown the parmeters m, β, ε_e and r can vary with the applied voltage
- We can rewrite the Thornton equation for any voltage

$$\frac{1}{V_{\rm D}} = \frac{\beta m \epsilon_{\rm e} (1-r)}{\mathcal{E}_{\rm c}} \gamma_{\rm SE}$$

A low-pressure cold-cathode discharge is maintained primarily by secondary electrons emitted from the cathode by ion bombardment. These electrons are accelerated in the CDS and enter the plasma where, known as primary electrons, they must produce sufficient ions to release one further electron from the cathode.⁷² This requirement can be expressed by the following relationship for the minimum potential to sustain such a discharge:⁷³

$$V_{\min} = \mathcal{E}_0 / \Gamma_i \epsilon_i \epsilon_e \qquad (5)$$

Thornton (1978) JVST 15(2) 171



- A plot of the inverse discharge voltage $1/V_{\rm D}$ against $\gamma_{\rm SE}$ should then give a straight line through the origin
- Depla et al. measured the discharge voltage for a 5 cm diameter target for Ar working gas for 18 different target materials
- Since all the data is taken in the same magnetron, at same current and pressure, the discharge parameters parmeters *m*, β, ε_e and *ε*_c are independent of γ_{SE}





From Depla et al. (2009) TSF 517 2825

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- 1/V_D against γ_{SE} for gas pressures of 0.4 and 0.6 Pa and discharge currents 0.4 A and 0.6 A
- It can be seen that a straight line indeed results, but that it does not pass through the origin

- We here propose that the intercept is due to Ohmic heating
- We can now write the inverse discharge voltage $1/V_{\rm D}$ in the form of a generalized Thornton equation

$$\frac{1}{V_{\rm D}} = \underbrace{\frac{\beta \epsilon_{\rm e}^{\rm H} m (1-r) (1-\delta_{\rm IR})}{\mathcal{E}_{\rm c}^{\rm H}}}_{a} \gamma_{\rm SE} + \underbrace{\frac{\epsilon_{\rm e}^{\rm C} \langle l_{\rm e}/l_{\rm D} \rangle_{\rm IR} \delta_{\rm IR}}{\mathcal{E}_{\rm c}^{\rm C}}}_{b}$$
or
$$\frac{1}{V_{\rm D}} = a \gamma_{\rm SE} + b$$

- We associate a with hot electrons e^H, sheath acceleration
- We associate b with the Ohmic heating process and cold electrons e^C



- The figure shows schematically the magnetic field lines and the electric equipotential surfaces above the racetrack
- A potential $V_{\rm SH}$ falls over the sheath, and the rest of the applied voltage, $V_{\rm IR} = V_{\rm D} - V_{\rm SH}$, falls across the extended pre-sheath, the ionization region (IR), $\delta_{\rm IR} = V_{\rm IR}/V_{\rm D}$
- Ohmic heating, the dissipation of locally deposited electric energy
 J_e · E to the electrons in the plasma volume outside the sheath



From Brenning et al. (2016) PSST 25 065024



I _D (A)	p (Pa)	Slope k	Intercept 1	$\delta_{\rm IR} = U_{\rm IR}/U_{\rm D}$
0.4	0.4	0.0117	0.00145	0.19
0.4	0.6	0.0129	0.00120	0.16
0.6	0.4	0.0130	0.00130	0.17
0.6	0.6	0.0140	0.00110	0.15

- It follows that the fraction of the total ionization that is due to Ohmic heating can be obtained directly from the line fit parameters a and b
- This can be written as a function of only the secondary electron yield

 $\gamma_{\rm SE}$

$$\frac{\iota_{\rm Ohmic}}{\iota_{\rm total}} = \frac{b}{a\gamma_{\rm SE} + b}$$



$I_{\rm D}({\rm A})$	p (Pa)	Slope k	Intercept l	$\delta_{\rm IR} = U_{\rm IR}/U_{\rm D}$
0.4	0.4	0.0117	0.00145	0.19
0.4	0.6	0.0129	0.00120	0.16
0.6	0.4	0.0130	0.00130	0.17
0.6	0.6	0.0140	0.001 10	0.15

 The fraction of the discharge voltage that falls over the ionization region

$$\delta_{\rm IR} = \frac{V_{\rm IR}}{V_{\rm D}}$$

can be estimated from

$$b = \frac{\epsilon_{\rm e}^{\rm C} \langle I_{\rm e} / I_{\rm D} \rangle_{\rm IR} \delta_{\rm IR}}{\mathcal{E}_{\rm c}^{\rm C}}$$

We assume $\epsilon_{\rm e}^{\rm C} = 0.8, \quad \langle I_{\rm e}/I_{\rm D}\rangle_{\rm IR} \approx 0.5,$ and $\mathcal{E}_{c}^{C} = 53.5 \text{ V} \text{ for } T_{e} = 3 \text{ V}$ which gives $\delta_{IR} = 0.15 - 0.19$ • 15 - 19 % of the applied discharge voltage fall over

the ionization region

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- Recent measurements have revealed strong electric fields parallel and perpendicular to the target of a dc magnetron sputtering discharge
- Electrons gain energy when they encounter an electric field – a potential gradient, such as the field in the double layer
- The electron heating power J_e · E is associated with an acceleration of electrons in the electric field – this electron energization in a double layer is Ohmic heating



From Panjan and Anders (2017) JAP 121 063302

• The distribution of $V_{\rm p} - V_{\rm f} \propto \langle E \rangle$ in the r - z plane for a dcMS operated at 270 V and 0.27 Pa

On electron heating in magnetron sputtering discharges

High power impulse magnetron sputtering discharge



High power impulse magnetron sputtering discharge

- High ionization of sputtered material requires very high density plasma
- In a conventional dc magnetron sputtering discharge the power density (plasma density) is limited by the thermal load on the target
- High power pulsed magnetron sputtering (HPPMS)
- In a HiPIMS discharge a high power pulse is supplied for a short period
 - Iow frequency
 - Iow duty cycle
 - Iow average power



Gudmundsson et al. (2012), JVSTA 30 030801

- Power density limits
 - $p_t = 0.05 \text{ kW/cm}^2 \text{ dcMS}$ limit
 - $p_{\rm t} = 0.5 \ {\rm kW/cm^2} \ {\rm HiPIMS} \ {\rm limit}$



On electron heating in magnetron sputtering discharges

Ionization region model studies of non-reactive HiPIMS



- The ionization region model (IRM) was developed to improve the understanding of the plasma behaviour during a HiPIMS pulse and the afterglow
- The main feature of the model is that an ionization region (IR) is defined next to the race track
- The IR is defined as an annular cylinder with outer radii r_{c2} , inner radii r_{c1} and length $L = z_2 - z_1$, extends from z_1 to z_2 axially away from the target



The definition of the volume covered by the IRM From Raadu et al. (2011). PSST 20 065007



- The temporal development is defined by a set of ordinary differential equations giving the first time derivatives of
 - the electron energy
 - the particle densities for all the particles
- The species assumed in the non-reactive-IRM are
 - cold electrons e^C (Maxwellian), hot electrons e^H (sheath acceleration)
 - argon atoms Ar(3s²3p⁶), warm argon atoms in the ground state Ar^W, hot argon atoms in the ground state Ar^H, Ar^m (1s₅ and 1s₃) (11.6 eV), argon ions Ar⁺ (15.76 eV)
 - titanium atoms Ti(a³F), titanium ions Ti⁺ (6.83 eV), doubly ionized titanium ions Ti²⁺ (13.58 eV)
 - aluminium atoms Al(²P_{1/2}), aluminium ions Al⁺ (5.99 eV), doubly ionized aluminium ions Al²⁺ (18.8 eV)

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- The model is constrained by experimental data input and fitted to reproduce the measured discharge current and voltage curves, *I*_D(*t*) and *V*_D(*t*), respectively
- Two model fitting parameters were found to be sufficient for a discharge with Al target
 - *V*_{IR} accounts for the power transfer to the electrons
 - β is the probability of back-attraction of ions to the target

From Huo et al. (2017), JPD 50 354003

Experimental data from Anders et al. (2007) JAP 102 113303



- A non-reactive discharge with Al target
- When the discharge is operated at 400 V the contributions of Al⁺ and Ar⁺-ions to the discharge current are very similar
- At 800 V Al⁺-ions dominate the discharge current (self-sputtering) while the contribution of Ar⁺ is below 10 % except at the initiation of the pulse

From Huo et al. (2017), JPD 50 354003

Experimental data from Anders et al. (2007) JAP 102 113303



- A primary current *I*_{prim} is defined as ions of the working gas, here Ar⁺, that are ionized for the first time and then drawn to the target
- This is the dominating current in dc magnetron sputtering discharges
- This current has a critical upper limit

$$I_{\rm crit} = S_{
m RT} e p_{
m g} \sqrt{rac{1}{2\pi m_{
m g} k_{
m B} T_{
m g}}} = S_{
m RT} e n_{
m g} \sqrt{rac{k_{
m B} T_{
m g}}{2\pi m_{
m g}}}$$

 Discharge currents *I*_D above *I*_{crit} are only possible if there is some kind of recycling of atoms that leave the target, become subsequently ionized and then are drawn back to the target

Anders et al. (2012), JPD 45 012003



Huo et al-(2014) PSST 23 025017 0 0

- For the AI target the critical current is $I_{\rm crit} \approx$ 7 A
- The experiment is operated from far below *I*_{crit} to high above it, up to 36 A.
- With increasing current *I*_{prim} gradually becomes a very small fraction of the total discharge current *I*_D
- The current becomes mainly carried by singly charged Al⁺ ions, meaning that self-sputter recycling or the current I_{SS-recycle} dominates

From Huo et al. (2017), JPD 50 354003

Experimental data from Anders et al. (2007) JAP 102 113303



- Recall that singly charged metal ions cannot create the secondary electrons – for metal self-sputtering (γ_{SE} is practically zero)
- The first ionization energies of many metals are insufficient to overcome the workfunction of the target material
- For the discharge with AI target operated at high voltage, self-sputter dominated, the effective secondary electron emission is essentially zero



From Anders (2008) APL 92 201501



The power transfer to the electrons is given by

$$P_{e} = P_{SH} + P_{Ohm} = I_{e,SH} (V_{D} - V_{IR}) + \frac{I_{D} V_{IR}}{2}$$

where

$$P_{\rm SH} = I_{\rm e,SH} V_{\rm SH} = \left(I_{\rm Ar^+} \gamma_{\rm Ar^+,eff} + \frac{1}{2} I_{\rm M^{2+}} \gamma_{\rm M^{2+},eff} \right) V_{\rm SH}$$

and

$$P_{\text{Ohm}} = I_{e,\text{IR}} V_{\text{IR}} = \left\langle \frac{J_e}{J_D} \right\rangle I_D V_{\text{IR}}$$

• Then $I_{e,SH} \sim \gamma_{SE} \epsilon_e m(1-r) I_D \sim 0.05 I_D$ and $I_{e,SH} \ll I_D/2$ so that

$$\textit{I}_{e,SH} \ll \textit{I}_{D}/2$$

and Ohmic heating is more efficient



- For the AI target, the fraction of the total electron heating that is attributable to Ohmic heating is found in the range of 0.87 (360 V) to 0.99 (1000 V).
- The domination of Al⁺-ions, which have zero secondary electron emission yield, has the consequence that there is negligible sheath energization
- The ionization threshold for twice ionized Al²⁺, 18.8 eV, is so high that few such ions are produced



From Huo et al. (2017), JPD 50 354003



- The discharge with the Ti target is operated with peak current far above the critical current of $I_{\rm crit} \approx 19$ A
- This discharge shows close to a 50/50 combination of self-sputter recycling l_{SS-recycle} and working gas-recycling l_{gas-recycle}
- The fraction of the total electron heating that is attributable to Ohmic heating is about 92 %

From Huo et al. (2017), JPD 50 354003

Experimental data from Bradley et al. (2015) JPD 48 215202



- The relative contributions to the total ionization ι_{total} due to Ohmic heating, ι_{Ohmic}, and sheath energization, ι_{sheath}
- A blue circle marks the HiPIMS study modelled by Huo et al. (2013)
- It is taken at the end of a 400 μs long pulse when the discharge was deep into the self-sputtering mode
- A large fraction of Al⁺ ions here gives γ_{SE,eff} close to zero
- Note that this HiPIMS case $\gamma_{\rm SE,eff}$ is consistent with the dcMS cases





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Summary



Summary

- It has been demonstrated that Ohmic heating of the electrons can play a significant role in conventional dc magnetron sputtering discharges
- We used a ionization region model to explore the plasma composition and the electron heating mechanism in a high power impulse magnetron sputtering (HiPIMS) discharge
 - For high currents the discharge with AI target develops almost pure **self-sputter recycling**, while the discharge with Ti target exhibits close to a 50/50 combination of **self-sputter recycling** and **working gas-recycling**
 - The fraction of the total electron heating that is attributable to Ohmic heating is over 90 % in the HiPIMS discharge



On electron heating in magnetron sputtering discharges

Thank you for your attention

The slides can be downloaded at

http://langmuir.raunvis.hi.is/~tumi/ranns.html
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200